

IPG20N04S4L11AATMA1

IPG20N04S4L11AATMA1 Information





Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPG20N04S4L11AATMA1 Specifications

	Report errors?
Supplier Device Package	PG-TDSON-8-10
Package / Case	8-PowerVDFN
Mounting Type	Surface Mount
Operating Temperature	-55°C ~ 175°C (TJ)
Power - Max	41W
Input Capacitance (Ciss) (Max) @ Vds	1990pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	26nC @ 10V
Vgs(th) (Max) @ Id	2.2V @ 15µA
Rds On (Max) @ Id, Vgs	11.6 mOhm @ 17A, 10V
Current - Continuous Drain (Id) @ 25°C	20A
Drain to Source Voltage (Vdss)	40V
FET Feature	Logic Level Gate
FET Type	2 N-Channel (Dual)
Series	Automotive, AEC-Q101, OptiMOS?
Package	8-PowerVDFN
	Transistors - FETs, MOSFETs - Arrays
Category	Discrete Semiconductor Products
Manufacturer	Infineon Technologies
Manufacturer Part Number	IPG20N04S4L11AATMA1

IPG20N04S4L11AATMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPG20N04S4L11AATMA1 Payment Methods



If you have any question about IPG20N04S4L11AATMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com